

TLP598G

Telecommunication  
Data Acquisition  
Measurement Instrumentation

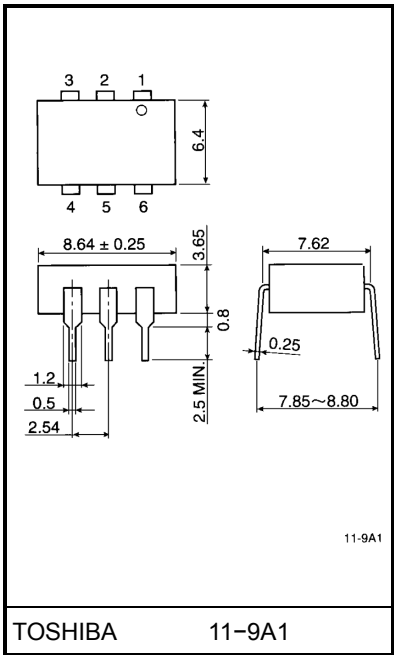
The TOSHIBA TLP598G consists of an aluminum gallium arsenide infrared emitting diode optically coupled to a photo-MOS FET in a six lead plastic DIP package (DIP6).  
The TLP598G is a bi-directional switch which can replace mechanical relays in many applications.

- Peak off-state voltage: 400 V (min.)
- On-state current: 150 mA (max.) (A connection)
- On-state resistance: 12 Ω (max.) (A connection)
- Isolation voltage: 2500 Vrms (min.) (A connection)
- UL recognized: UL1577, file no. E67349
- Trigger LED current (Ta = 25°C)

| Classification<br>(Note 1) | Trigger LED Current<br>(mA) |      | Marking Of<br>Classification |
|----------------------------|-----------------------------|------|------------------------------|
|                            | @I <sub>ON</sub> = 150 mA   |      |                              |
|                            | Min.                        | Max. |                              |
| (IFT2)                     | —                           | 2    | T2                           |
| Standard                   | —                           | 5    | T2, blank                    |

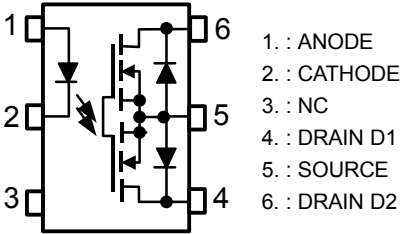
(Note 1): Application type name for certification test,  
please use standard product type name, i.e.  
TLP598G (IFT2): TLP598G

Unit in mm

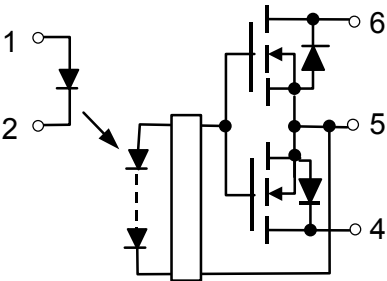


Weight: 0.49 g

Pin Configuration (top view)



Schematic



## Maximum Ratings (Ta = 25°C)

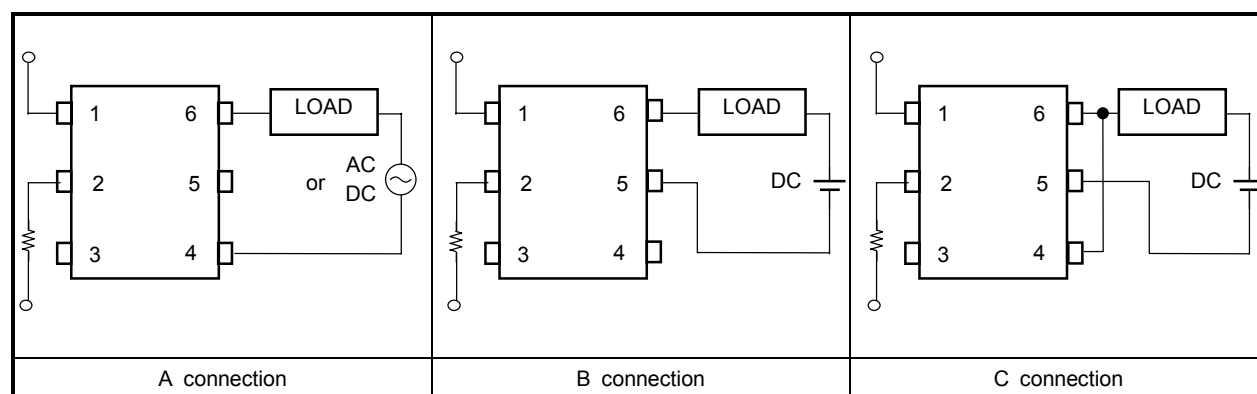
| Characteristic                                      |                                              |                  | Symbol                | Rating           | Unit    |
|-----------------------------------------------------|----------------------------------------------|------------------|-----------------------|------------------|---------|
| LED                                                 | Forward current                              |                  | I <sub>F</sub>        | 30               | mA      |
|                                                     | Forward current derating (Ta ≥ 25°C)         |                  | ΔI <sub>F</sub> / °C  | −0.3             | mA / °C |
|                                                     | Peak forward current (100 μs pulse, 100 pps) |                  | I <sub>FP</sub>       | 1                | A       |
|                                                     | Reverse voltage                              |                  | V <sub>R</sub>        | 5                | V       |
|                                                     | Junction temperature                         |                  | T <sub>j</sub>        | 125              | °C      |
| Detector                                            | Off-state output terminal voltage            |                  | V <sub>OFF</sub>      | 400              | V       |
|                                                     | On-state RMS current                         | A connection     | I <sub>ON</sub>       | 150              | mA      |
|                                                     |                                              | B connection     |                       | 200              |         |
|                                                     |                                              | C connection     |                       | 300              |         |
|                                                     | On-state current derating (Ta ≥ 25°C)        | A connection     | ΔI <sub>ON</sub> / °C | −1.5             | mA / °C |
|                                                     |                                              | B connection     |                       | −2.0             |         |
|                                                     |                                              | C connection     |                       | −3.0             |         |
|                                                     | Junction temperature                         |                  | T <sub>j</sub>        | 125              | °C      |
| Storage temperature range                           |                                              | T <sub>stg</sub> | −55~125               | °C               |         |
| Operating temperature range                         |                                              | T <sub>opr</sub> | −40~85                | °C               |         |
| Lead soldering temperature (10 s)                   |                                              | T <sub>sol</sub> | 260                   | °C               |         |
| Isolation voltage (AC, 1 min., R.H. ≤ 60%) (Note 2) |                                              | BV <sub>S</sub>  | 2500                  | V <sub>rms</sub> |         |

(Note 2): Device considered a two-terminal device: Pins 1, 2 and 3 shorted together, and pins 4, 5 and 6 shorted together.

## Recommended Operating Conditions

| Characteristic        | Symbol    | Min. | Typ. | Max. | Unit |
|-----------------------|-----------|------|------|------|------|
| Supply voltage        | $V_{DD}$  | —    | —    | 320  | V    |
| Forward current       | $I_F$     | 10   | 15   | 20   | mA   |
| On-state current      | $I_{ON}$  | —    | —    | 150  | mA   |
| Operating temperature | $T_{opr}$ | -20  | —    | 80   | °C   |

## Circuit Connections



## Individual Electrical Characteristics (Ta = 25°C)

| Characteristic |                   | Symbol    | Test Condition             | Min. | Typ. | Max. | Unit          |
|----------------|-------------------|-----------|----------------------------|------|------|------|---------------|
| LED            | Forward voltage   | $V_F$     | $I_F = 10 \text{ mA}$      | 1.2  | 1.4  | 1.7  | V             |
|                | Reverse current   | $I_R$     | $V_R = 3 \text{ V}$        | —    | —    | 10   | $\mu\text{A}$ |
|                | Capacitance       | $C_T$     | $V = 0, f = 1 \text{ MHz}$ | —    | 30   | —    | pF            |
| Detector       | Off-state current | $I_{OFF}$ | $V_{OFF} = 400 \text{ V}$  | —    | —    | 1    | $\mu\text{A}$ |
|                | Capacitance       | $C_{OFF}$ | $V = 0, f = 1 \text{ MHz}$ | —    | —    | —    | pF            |

## Coupled Electrical Characteristics (Ta = 25°C)

| Characteristic      |              | Symbol   | Test Condition                                 | Min. | Typ. | Max. | Unit     |
|---------------------|--------------|----------|------------------------------------------------|------|------|------|----------|
| Trigger LED current |              | $I_{FT}$ | $I_{ON} = 150 \text{ mA}$                      | —    | 1    | 5    | mA       |
| On-state resistance | A connection | $R_{ON}$ | $I_{ON} = 150 \text{ mA}, I_F = 10 \text{ mA}$ | —    | 8    | 12   | $\Omega$ |
|                     | B connection |          | $I_{ON} = 200 \text{ mA}, I_F = 10 \text{ mA}$ | —    | 4    | 6    |          |
|                     | C connection |          | $I_{ON} = 300 \text{ mA}, I_F = 10 \text{ mA}$ | —    | 2    | 3    |          |

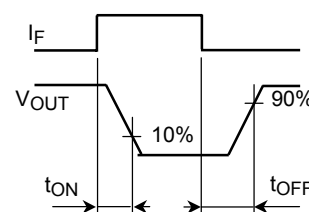
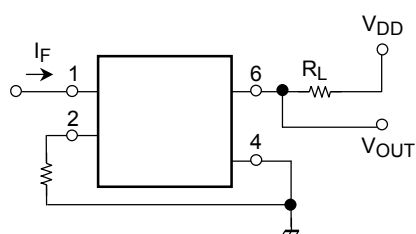
## Isolation Characteristics (Ta = 25°C)

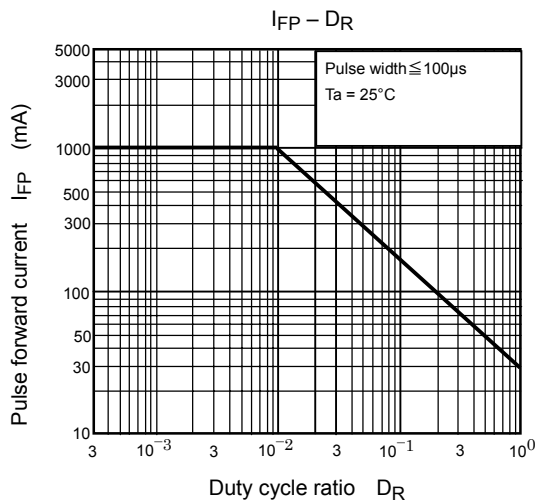
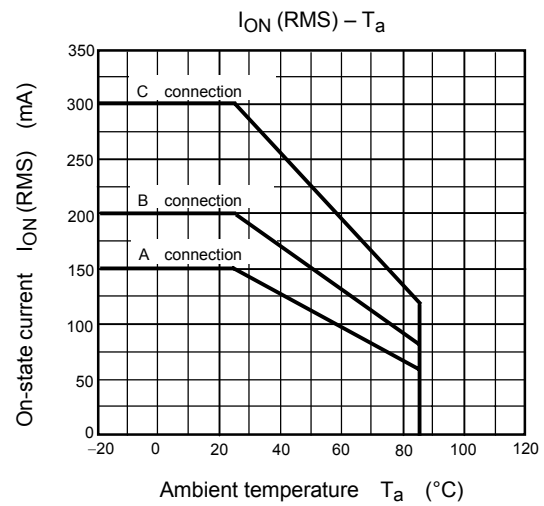
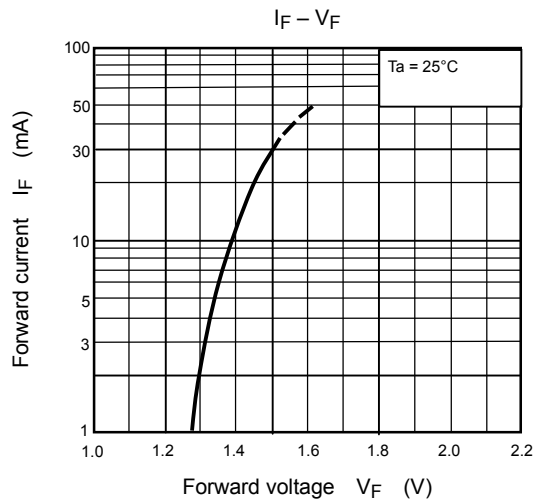
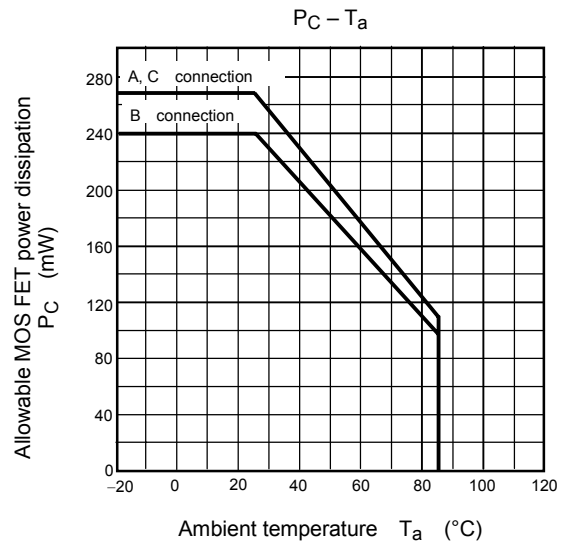
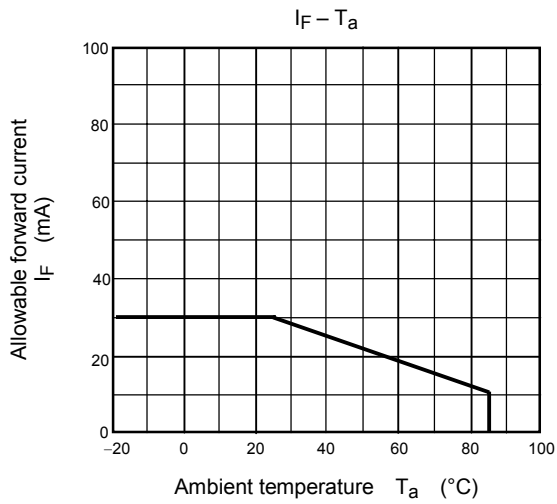
| Characteristic              | Symbol | Test Condition                               | Min.               | Typ.      | Max. | Unit      |
|-----------------------------|--------|----------------------------------------------|--------------------|-----------|------|-----------|
| Capacitance input to output | $C_S$  | $V_S = 0, f = 1 \text{ MHz}$                 | —                  | 0.8       | —    | pF        |
| Isolation resistance        | $R_S$  | $V_S = 500 \text{ V}, \text{R.H.} \leq 60\%$ | $5 \times 10^{10}$ | $10^{14}$ | —    | $\Omega$  |
| Isolation voltage           | $BV_S$ | AC, 1 minute                                 | 2500               | —         | —    | $V_{rms}$ |
|                             |        | AC, 1 second (in oil)                        | —                  | 5000      | —    |           |
|                             |        | DC, 1 minute (in oil)                        | —                  | 5000      | —    | $V_{DC}$  |

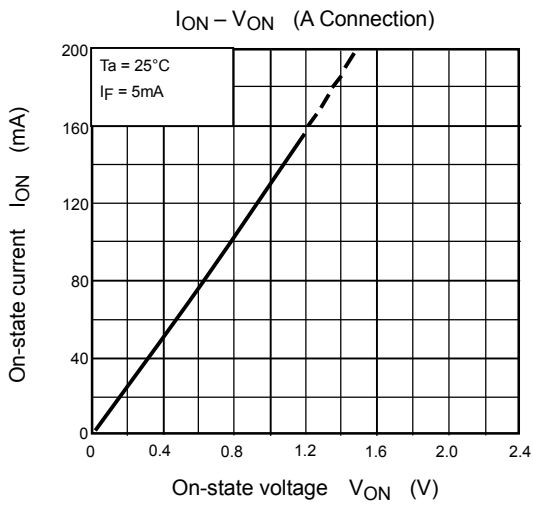
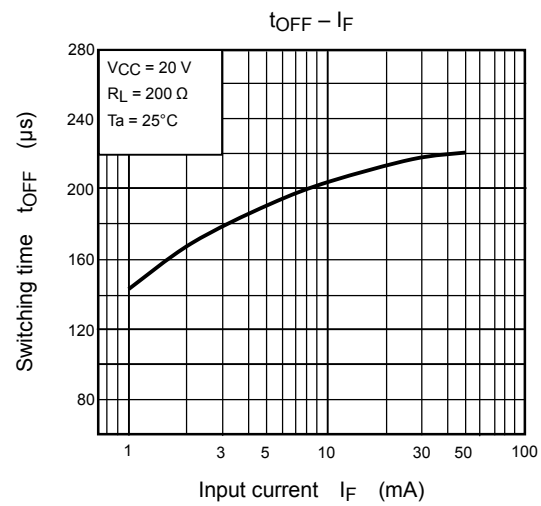
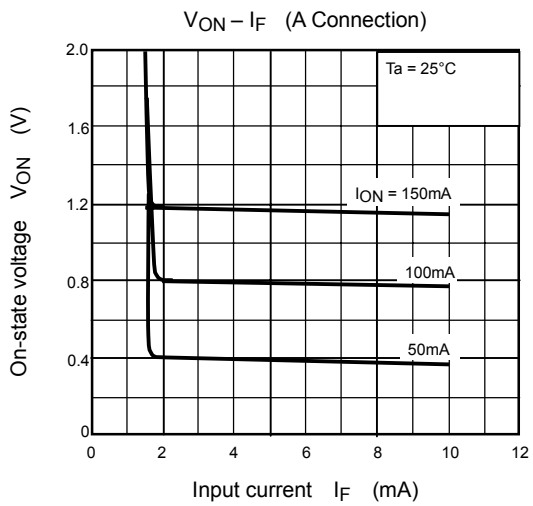
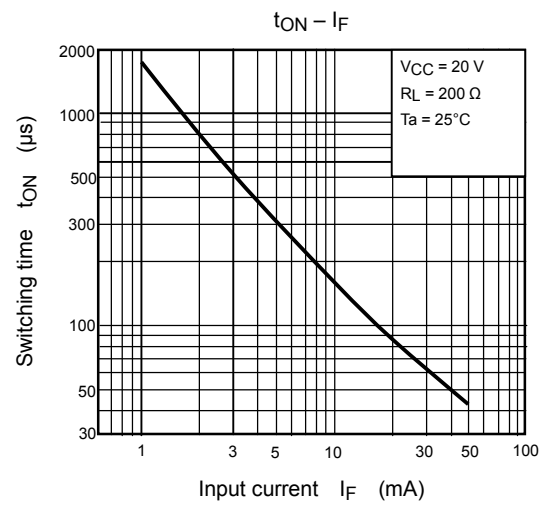
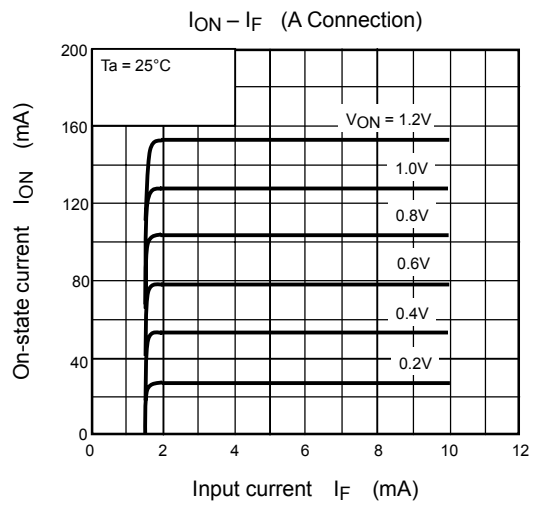
## Switching Characteristics (Ta = 25°C)

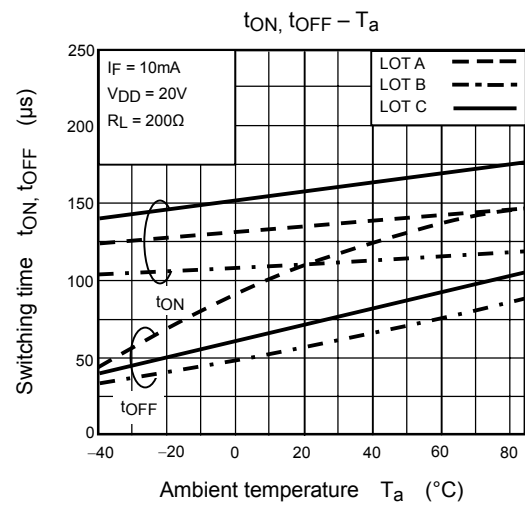
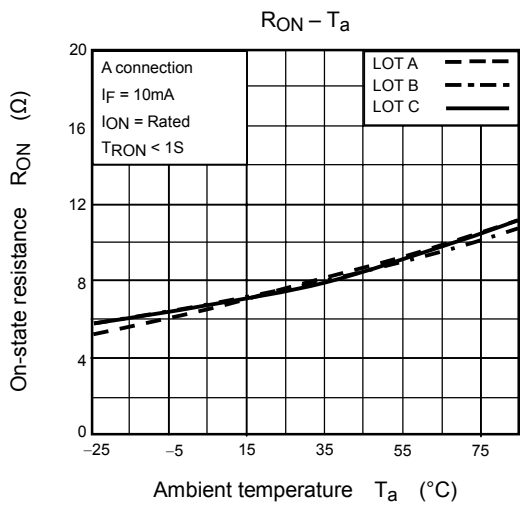
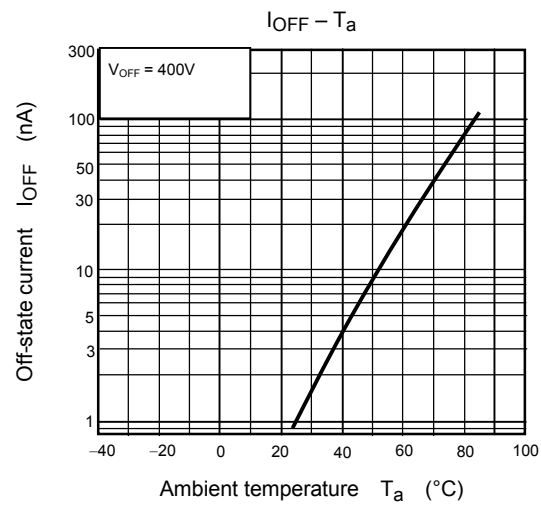
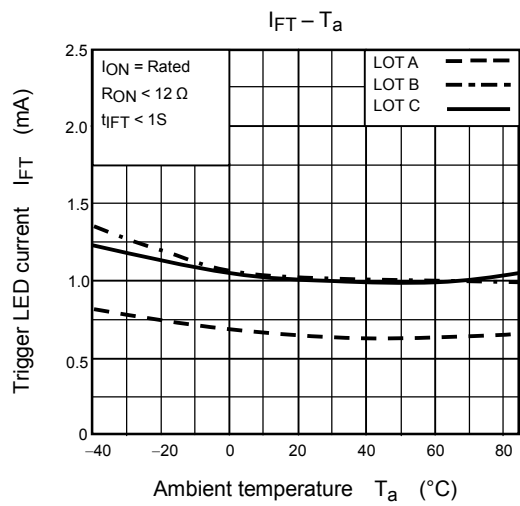
| Characteristic | Symbol    | Test Condition                                                              | Min. | Typ. | Max. | Unit |
|----------------|-----------|-----------------------------------------------------------------------------|------|------|------|------|
| Turn-on time   | $t_{ON}$  | $V_{DD} = 20 \text{ V}, R_L = 200 \Omega$<br>$I_F = 10 \text{ mA}$ (Note 3) | —    | 0.3  | 1.0  | ms   |
| Turn-off time  | $t_{OFF}$ |                                                                             | —    | 0.2  | 1.0  |      |

(Note 3): Switching time test circuit









**RESTRICTIONS ON PRODUCT USE**

000707EBC

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.  
In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- Gallium arsenide (GaAs) is a substance used in the products described in this document. GaAs dust and fumes are toxic. Do not break, cut or pulverize the product, or use chemicals to dissolve them. When disposing of the products, follow the appropriate regulations. Do not dispose of the products with other industrial waste or with domestic garbage.
- The products described in this document are subject to the foreign exchange and foreign trade laws.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.